



# EVERLIGHT ELECTRONICS CO., LTD.

DEVICE NUMBER : DPD-020-032

ECN : \_\_\_\_\_

REV : 1.1

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## 3mm Silicon PIN Photodiode

MODEL NO : PD202B

### ■ Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance

### ■ Description :

PD202B is a high speed and high sensitive PIN photodiode in a standard 3Φ plastic package. The device is spectrally matched to infrared emitting diode.

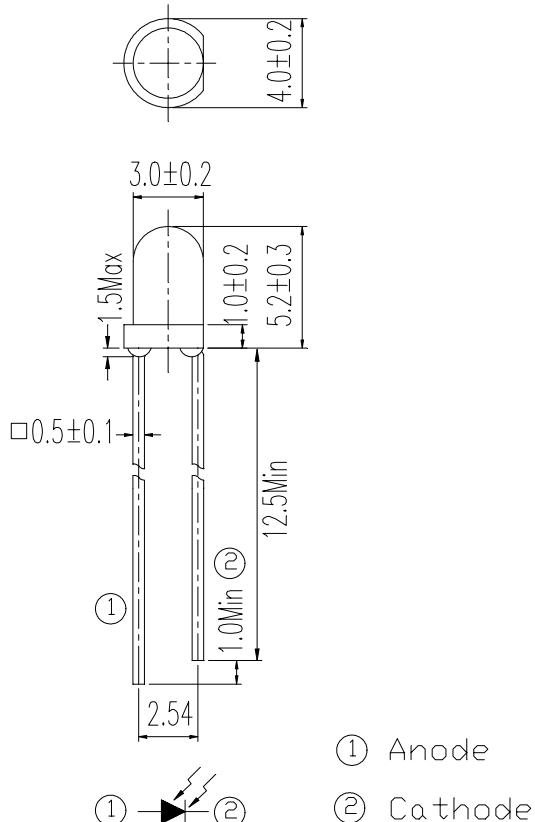
### ■ Applications :

- High speed photo detector
- Camera
- Optoelectronic switch
- VCRs ,Video camera
- Floppy disk drive

PART NO.	CHIP	LENS COLOR
	MATERIAL	
PD	Silicon	Black

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REV : 1.1PAGE : 2/7**3mm Silicon PIN Photodiode**MODEL NO : PD202B**■ Package Dimensions :****■ Notes :**

1. All dimensions are in millimeter.
2. Protruded resin under flange 1.5 mm Max.
3. Lead spacing is measured where the lead emerge from the package.
4. Lens color : Black.
5. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
6. These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
7. When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

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**3mm Silicon PIN Photodiode**

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**■ Absolute Maximum Ratings at  $T_A = 25^\circ\text{C}$** 

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	$V_R$	32	V	
Power Dissipation	Pd	150	mW	
Lead Soldering Temperature	Tsol	260	$^\circ\text{C}$	4mm from mold body less than 5 seconds
Operating Temperature	Topr	-25 ~ +85	$^\circ\text{C}$	
Storage Temperature	Tstg	-40 ~ +85	$^\circ\text{C}$	

**■ Electronic Optical Characteristics :**

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	840-1200	----	nm	-----
Wavelength of Peak Sensitivity	$\lambda_p$	----	980	----	nm	-----
Open-Circuit Voltage	$V_{oc}$	----	0.42	----	V	Ee=5m W/c m <sup>2</sup> $\lambda p=940\text{nm}$
Short-Circuit Current	$I_{sc}$	----	15	----	$\mu\text{A}$	Ee=5m W/c m <sup>2</sup> $\lambda p=940\text{nm}$ $V_R=5\text{V}$
Reverse Light Current	$I_L$	----	15	----	$\mu\text{A}$	Ee=0m W/c m <sup>2</sup> $V_R=10\text{V}$
Dark Current	$I_d$	----	----	10	nA	Ee=0m W/c m <sup>2</sup> $V_R=10\text{V}$
Reverse Breakdown Voltage	$BV_R$	32	170	----	V	Ee=0m W/c m <sup>2</sup> $I_R=100\mu\text{A}$
Total Capacitance	Ct	----	5	----	pF	Ee=0m W/c m <sup>2</sup> $V_R=5\text{V}, f=1\text{MHz}$
Rise/Fall Time	$t_r/t_f$	----	6/6	----	nS	$V_R=10\text{V}$ $R_L=1\text{K}\Omega$

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### ■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs.  
Ambient Temperature

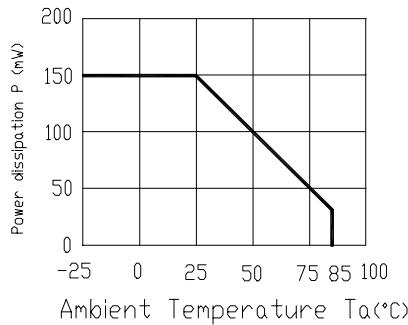


Fig. 2 Spectral Sensitivity

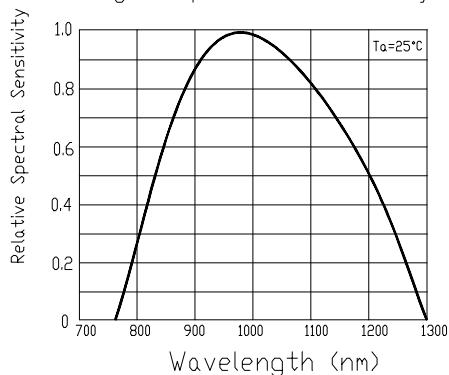


Fig.3 Dark Current vs.  
Ambient Temperature

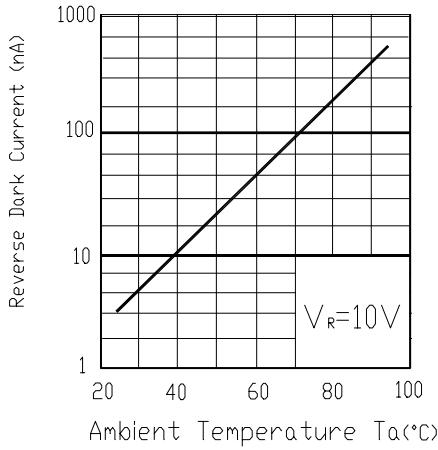


Fig.4 Reverse Light Current vs.Ee

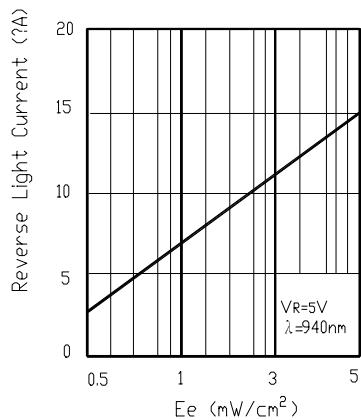


Fig.5 Terminal Capacitance vs.  
Revere Voltage

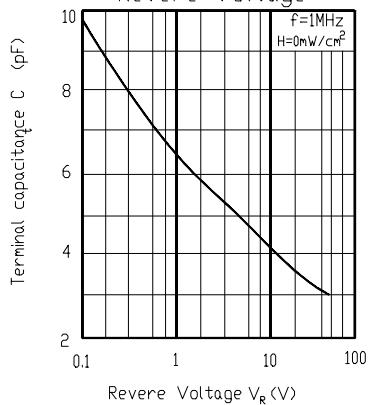
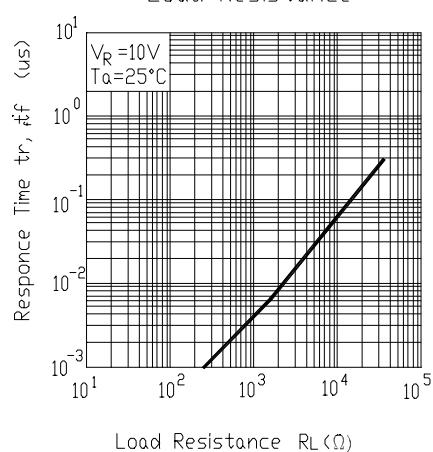


Fig.6 Responce Time vs.  
Load Resistance



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**■ Reliability Test Item And Condition**

The reliability of products shall be satisfied with items listed below.

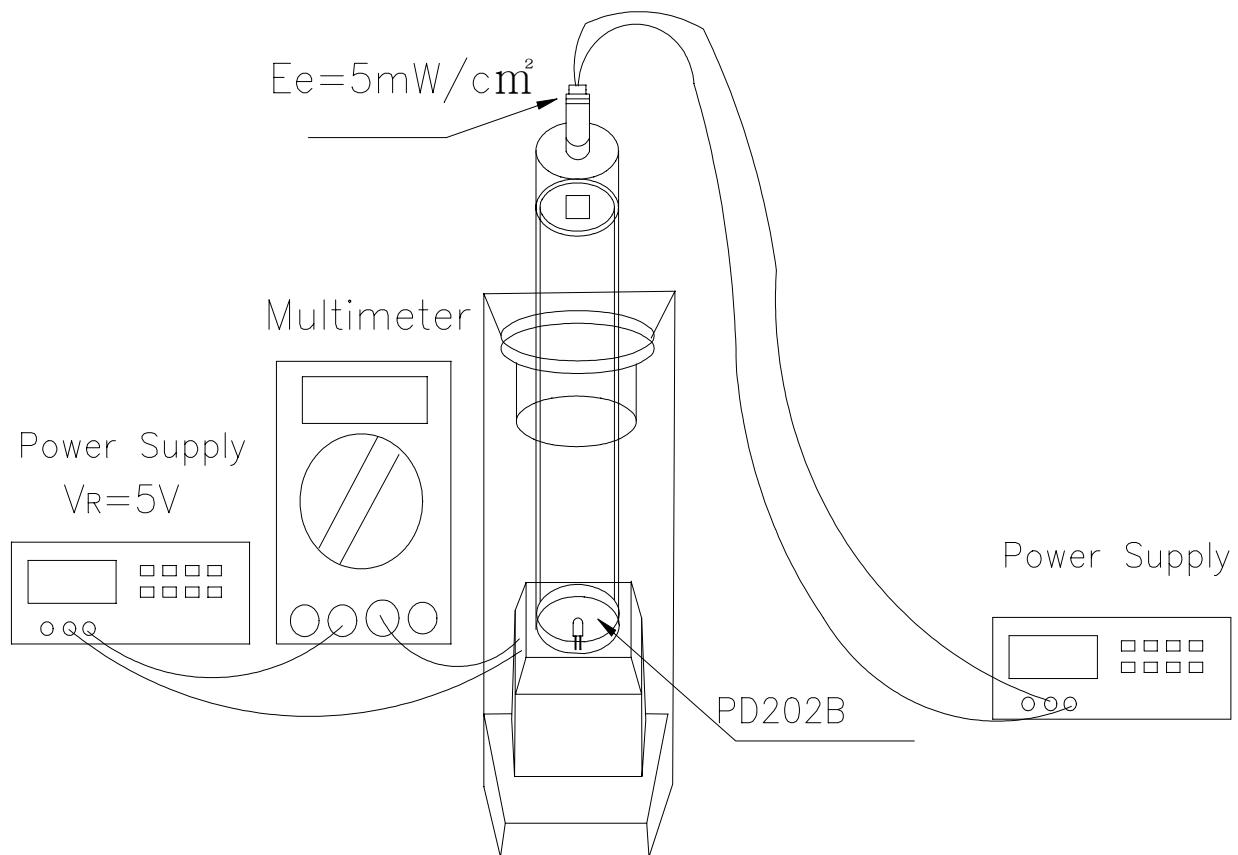
Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/Cycle	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP : 260°C ± 5 °C	5 secs	22 pcs		0/1
2	Temperature Cycle	H : +85°C 30 mins L : -55°C 30 mins	50 cycles	22 pcs	$I_L \leq L_x$ 0.8 L : Lower specification limit	0/1
3	Thermal Shock	H : +100°C 5 mins L : -10°C 5 mins	50 cycles	22 pcs		0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55°C	1000 hrs	22 pcs		0/1
6	DC Operating Life	$V_R=5V$	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85°C / 85% R.H.	1000 hrs	22 pcs		0/1

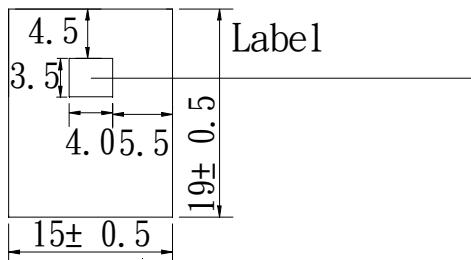
DEVICE NUMBER : DPD-020-032 REV : 1.1  
ECN : \_\_\_\_\_ PAGE : 6/7**3mm Silicon PIN Photodiode**MODEL NO : PD202B**■ Test Method For Reverse Light Current**Condition:  $E_e = 5 \text{ mW/cm}^2$ ,  $V_R = 5V$ 

Test Item: Reverse Light Current

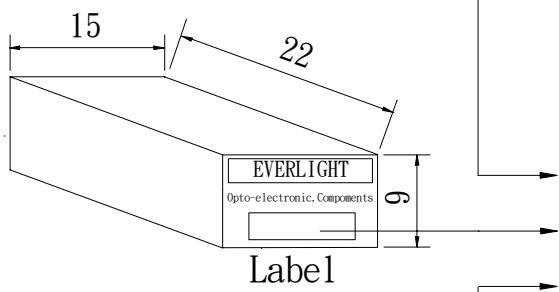
Unit :  $\mu\text{A}$ 

DEVICE NUMBER : DPD-020-032 REV : 1.1  
ECN : \_\_\_\_\_ PAGE : 7/7**3mm Silicon PIN Photodiode**MODEL NO : PD202B**■ Packing Specifications**

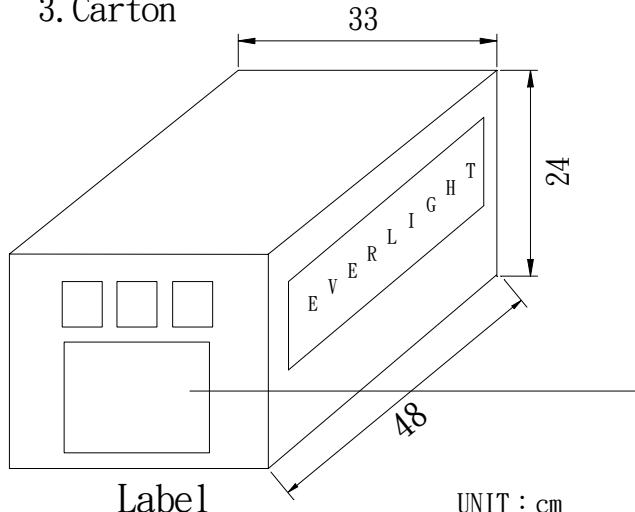
1. Bag



2. Box



3. Carton

**EVERLIGHT**

CPN:

P/N:



PD202B

QTY:



CAT:

HUE:

REF:

LOT NO:

MADE IN TAIWAN

CPN : Customer's Production Number

P/N : Production Number

QTY : Packing Quantity

CAT : Ranks

HUE : Peak Wavelength

REF : Reference

LOT NO : Lot Number

MADE IN TAIWAN : Production place

**■ Packing Quantity Specification**

1. 1000 Pcs/1Bag , 4 Bags/1Box
2. 10 Boxes/1Carton

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Datasheets for electronic components.